

**Micro Commercial Components** 



**Micro Commercial Components** 20736 Marilla Street Chatsworth CA 91311 Phone: (818) 701-4933 (818) 701-4939 Fax:

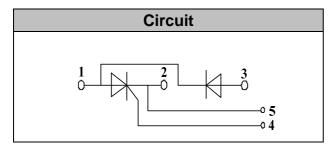
## **Features**

- Lead Free Finish/RoHS Compliant (NOTE 1)("P" Suffix designates RoHS Compliant. See ordering information)
- International standard package
- Heat transfer through aluminum oxide DBC ceramic isolated metal baseplate
- Glass passivated chip
- Simple Mounting

## Applications

- **Power Converters**
- Lighting Control
- DC Motor Control and Drives
- Heat and temperature control





MT110CB08T1 MT110CB12T1 MT110CB16T1 MT110CB18T1 **110 Amp THYRISTOR/DIODE** MODULE 800~1800 Volts T1 C‡ В D₫ LÎKŧ DIMENSIONS INCHES ΜN NOTE MIN MAX DIN MIN MAX 19.70 .799 20.30 .776 1.169 1.193 29.70 30.30 .343 .366 8.70 9.30 .323 .346 8.20 8.80 .622 15.80 6.30 .602 15.30 .224 .248 5.70 .539 .563 13.70 14.30 G н 16.70 17.30 .657 .681 3.138 3.161 79.70 80.30 3.65 3.673 92.70 93.30 Ø 10.70 11.30 .445 .421 20.70 21.30 .815 .839 Μ 14.70 15.30

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### Module Type

| ТҮРЕ        | Vrrm  | Vrsm  |
|-------------|-------|-------|
| MT110CB08T1 | 800V  | 900V  |
| MT110CB12T1 | 1200V | 1300V |
| MT110CB16T1 | 1600V | 1700V |
| MT110CB18T1 | 1800V | 1900V |

## ◆ Diode

### Maximum Ratings

| Symbol           | ltem                               | Conditions           | Values      | Units            |
|------------------|------------------------------------|----------------------|-------------|------------------|
| lD               | Output Current(D.C.)               | Tc=85℃               | 110         | А                |
| IFSM             | Surge forward current              | t=10mS Tvj =45℃      | 2250        | А                |
| i <sup>2</sup> t | Circuit Fusing Consideration       |                      | 25000       | A <sup>2</sup> s |
| Visol            | Isolation Breakdown Voltage(R.M.S) | a.c.50HZ;r.m.s.;1min | 3000        | V                |
| Tvj              | Operating Junction Temperature     |                      | -40 to +125 | °C               |
| Tstg             | Storage Temperature                |                      | -40 to +125 | °C               |
| Mt               | Mounting Torque                    | To terminals(M5)     | 3±15%       | Nm               |
| Ms               |                                    | To heatsink(M6)      | 5±15%       | Nm               |
| Weight           | Module (Approximately)             |                      | 100         | g                |

### **Thermal Characteristics**

| Symbol   | Item                    | Conditions       | Values | Units |
|----------|-------------------------|------------------|--------|-------|
| Rth(j-c) | Thermal Impedance, max. | Junction to Case | 0.14   | °C/W  |
| Rth(c-s) | Thermal Impedance, max. | Case to Heatsink | 0.10   | °C/W  |

### **Electrical Characteristics**

| Symbol | ltem                                  | Conditions                              | Values |            |      | Units    |
|--------|---------------------------------------|---|--------|------------|------|----------|
| Cymbol | nem                                   | Conditions                              | Min.   | Тур.       | Max. | Units    |
| VFM    | Forward Voltage Drop, max.            | T=25℃ IF =300A                          |        |            | 1.65 | V        |
| Irrm   | Repetitive Peak Reverse Current, max. | Tvj =25℃ VRD=VRRM<br>Tvj =125℃ VRD=VRRM |        | ≤0.5<br>≤6 |      | mA<br>mA |

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# Thyristor Maximum Ratings

| Symbol           | Item Conditions                                  |   | Values         | Units            |
|------------------|--|---|----------------|------------------|
| I <sub>TAV</sub> | Average On-State Current                         | Sine 180°;Tc=85℃  | 110            | Α                |
| I <sub>TSM</sub> | Surge On-State Current                           | T <sub>vJ</sub> =45℃ t=10ms, sine<br>T <sub>vJ</sub> =125℃ t=10ms, sine | 2250<br>1900   | А                |
| i <sup>2</sup> t | Circuit Fusing Consideration                     | $T_{VJ}$ =45°C t=10ms, sine<br>$T_{VJ}$ =125°C t=10ms, sine             | 25000<br>18000 | A2s              |
| Visol            | Isolation Breakdown Voltage(R.M.S)               | a.c.50HZ;r.m.s.;1min  | 3000           | V                |
| Tvj              | Operating Junction Temperature                   |   | -40 to +130    | °C               |
| Tstg             | Storage Temperature                              |   | -40 to +125    | °C               |
| Mt               | Mounting Torque                                  | To terminals(M5)  | 3±15%          | Nm               |
| Ms               |  | To heatsink(M6)   | 5±15%          | Nm               |
| di/dt            | Critical Rate of Rise of On-State<br>Current     | $T_{VJ}\text{=}~T_{VJM}$ , 2/3V_{DRM} ,I_G =500mA Tr<0.5us,tp>6us       | 150            | A/us             |
| dv/dt            | Critical Rate of Rise of Off-State Voltage, min. | $T_{\rm J}\text{=}T_{\rm VJM}$ ,2/3V_{\rm DRM} linear voltage rise      | 1000           | V/us             |
| а                | Maximum allowable acceleration                   |   | 50             | m/s <sup>2</sup> |

### **Thermal Characteristics**

| Symbol   | Item                    | Conditions       | Values | Units |
|----------|-------------------------|------------------|--------|-------|
| Rth(j-c) | Thermal Impedance, max. | Junction to Case | 0.28   | °C/W  |
| Rth(c-s) | Thermal Impedance, max. | Case to Heatsink | 0.20   | °C/W  |

### **Electrical Characteristics**

| Symbol                             | Itom  | Conditions  | Value | S    | Unito |
|------------------------------------|---|---|-------|------|-------|
| Symbol                             | Item  | Conditions  |       |      | Units |
| V <sub>TM</sub>                    | Peak On-State Voltage, max.   | T=25℃ I <sub>T</sub> =300A  |       | 1.65 | V     |
| I <sub>RRM</sub> /I <sub>DRM</sub> | Repetitive Peak Reverse Current,<br>max. / Repetitive Peak Off-State<br>Current, max. | T <sub>VJ</sub> =T <sub>VJM</sub> ,V <sub>R</sub> =V <sub>RRM</sub> ,V <sub>D</sub> =<br>V <sub>DRM</sub> |       | 20   | mA    |
| V <sub>TO</sub>                    | On state threshold voltage  | For power-loss<br>calculations only<br>(T <sub>VJ</sub> =125℃)  |       | 0.9  | V     |
| r <sub>T</sub>                     | Value of on-state slope resistance. max   | T <sub>VJ</sub> =T <sub>VJM</sub>   |       | 2    | mΩ    |
| V <sub>GT</sub>                    | Gate Trigger Voltage, max.  | T <sub>VJ</sub> =25℃ , V <sub>D</sub> =6V   |       | 3    | V     |
| I <sub>GT</sub>                    | Gate Trigger Current, max.  | $T_{VJ}$ =25 $^{\circ}$ C , $V_{D}$ =6V   |       | 150  | mA    |
| $V_{GD}$                           | Non-triggering gate voltage, max.   | T <sub>VJ</sub> =125℃,V <sub>D</sub> =2/3V <sub>DRM</sub>   |       | 0.25 | V     |
| I <sub>GD</sub>                    | Non-triggering gate current, max.   | T <sub>VJ</sub> =125℃, V <sub>D</sub> =2/3V <sub>DRM</sub>  |       | 6    | mA    |
| ١                                  | Latching current, max.  | $T_{VJ}$ =25 $^\circ C$ , $R_G$ = 33 $\Omega$   | 300   | 600  | mA    |
| I <sub>H</sub>                     | Holding current, max.   | T <sub>VJ</sub> =25℃, V <sub>D</sub> =6V  | 150   | 250  | mA    |
| tgd                                | Gate controlled delay time  | TVJ=25℃,<br>IG=1A, diG/dt=1A/us   | 1     |      | us    |
| tq                                 | Circuit commutated turn-off time  | $T_{VJ} = T_{VJM}$  | 100   |      | us    |

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### **Performance Curves**



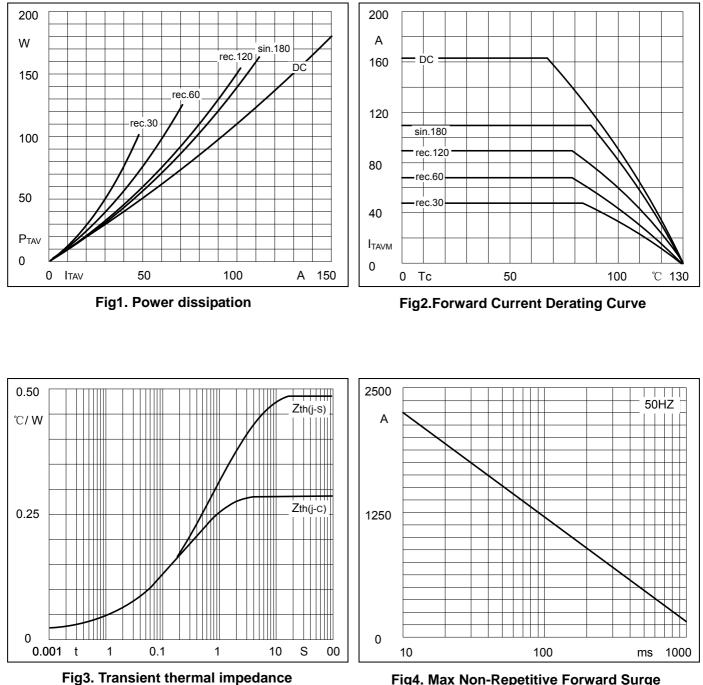


Fig4. Max Non-Repetitive Forward Surge Current

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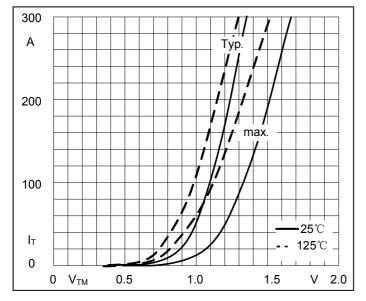


Fig5. Forward Characteristics

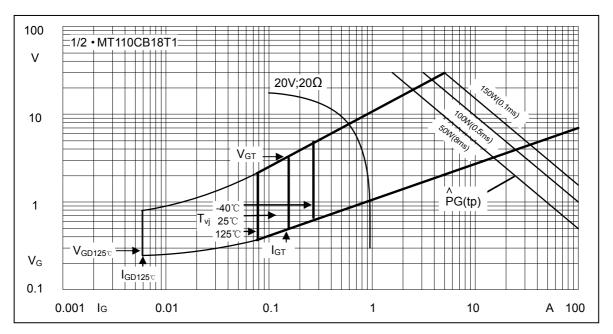


Fig6. Gate trigger Characteristics

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### **Revision:** A



### **Ordering Information :**

| Device         | Packing                     |
|----------------|-----------------------------|
| Part Number-BP | Bulk: 10PCS/BOX ;100PCS/CTN |

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